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2N5679 2N5680 PNP
2N5681 2N5682 NPN

COMPLEMENTARY SILICON
HIGH POWER TRANSISTORS

JEDEC TO-39 CASE

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

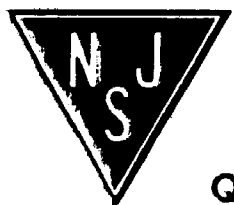
	SYMBOL	2N5679 2N5681	2N5680 2N5682	UNITS
Collector-Base Voltage	V_{CB0}	100	120	V
Collector-Emitter Voltage	V_{CE0}	100	120	V
Emitter-Base Voltage	V_{EB0}		4.0	V
Collector Current	I_C		1.0	A
Base Current	I_B		0.5	A
Power Dissipation	P_D		1.0	W
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D		10	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200		$^\circ\text{C}$
Thermal Resistance	Θ_{JA}	175		$^\circ\text{C/W}$
Thermal Resistance	Θ_{JC}	17.5		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	2N5679 2N5681		2N5680 2N5682		UNITS
		MIN	MAX	MIN	MAX	
I_{CB0}	$V_{CB} = \text{Rated } V_{CB0}$		1.0		1.0	μA
I_{CEV}	$V_{CE} = \text{Rated } V_{CE0}, V_{EB} = 1.5\text{V}$		1.0		1.0	μA
I_{CEV}	$V_{CE} = \text{Rated } V_{CE0}, V_{EB} = 1.5\text{V}, T_C = 150^\circ\text{C}$		1.0		1.0	mA
I_{CE0}	$V_{CE} = 70\text{V}$		10		---	μA
I_{CE0}	$V_{CE} = 80\text{V}$		---		10	μA
I_{EBO}	$V_{EB} = 4.0\text{V}$		1.0		1.0	μA
BV_{CE0}	$I_C = 10\text{mA}$	100		120		V
$V_{CE(\text{SAT})}$	$I_C = 250\text{mA}, I_B = 25\text{mA}$		0.6		0.6	V
$V_{CE(\text{SAT})}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$		1.0		1.0	V
$V_{CE(\text{SAT})}$	$I_C = 1.0\text{A}, I_B = 200\text{mA}$		2.0		2.0	V
$V_{BE(\text{ON})}$	$V_{CE} = 2.0\text{V}, I_C = 250\text{mA}$		1.0		1.0	V
h_{FE}	$V_{CE} = 2.0\text{V}, I_C = 250\text{mA}$	40	150	40	150	
h_{FE}	$V_{CE} = 2.0\text{V}, I_C = 1.0\text{A}$	5.0		5.0		

NJ Semi-Conductors reserves the right to change test conditions, parameters limits and package dimensions without notice information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

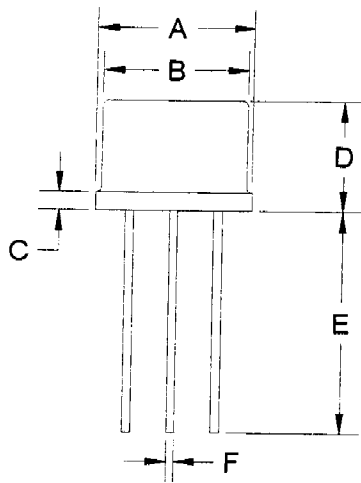
Quality Semi-Conductors



ELECTRICAL CHARACTERISTICS CONTINUED ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	2N5679 2N5681		2N5680 2N5682		UNITS
		MIN	MAX	MIN	MAX	
h_{fe}	$V_{CE}=1.5\text{V}, I_C=0.2\text{A}, f=1.0\text{kHz}$	40		40		
f_T	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=10\text{MHz}$	30		30		MHz
C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1.0\text{MHz}$		50		50	pF

TO-39 PACKAGE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.335	0.370	8.51	9.40
B (DIA)	0.315	0.335	8.00	8.51
C	-	0.040	-	1.02
D	0.240	0.260	6.10	6.60
E	0.500	-	12.70	-
F (DIA)	0.016	0.021	0.41	0.53
G (DIA)	0.200		5.08	
H	0.100		2.54	
I	0.028	0.034	0.71	0.86
J	0.029	0.045	0.74	1.14

TO-39 (REV: R1)

